NSN 5961-00-100-1183

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-100-1183 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.450 inches Overall Diameter: 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 275.0 breakdown voltage, collector-to-base, emitter open and 6.0 breakdown voltage, emitter-to-base, collector open and 275.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 3.00 amperes source cutoff current and 1.500 amperes source cutoff current **Power Rating Per Characteristic:** 57.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 1 case and 2 pin **Specification Data:** 80131-release6048 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No